

RFM75替换RFM73注意事项

一、软件设置注意事项:

1. Bank1 SPI 设置

RFM75 bank1 SPI 操作与 RFM73相同。

采用 RFM73 的 bank1 设置,芯片可以正常工作,为了获得更好的性能,建议 bank1 采用以下设置。

Bank1	250KHz	1MHz	2MHz		
Address (Hex)					
00	Reserved	Reserved	Reserved		
01	Reserved	Reserved	Reserved		
02	Reserved	Reserved	Reserved		
03	Reserved	Reserved	Reserved		
04	0xDB8A96F9	0x1B8296F9	0xDB8296F9		
05	0xB60F0624	0xA60F0624	0xB60F0624		
06	Reserved	Reserved	Reserved		
07	Reserved	Reserved	Reserved		
08	Reserved	Reserved	Reserved		
09	Reserved	Reserved	Reserved		
0A	Reserved	Reserved	Reserved		
0B	Reserved	Reserved	Reserved		
0C	0x00127300	0x00127300	0x00127300		
0D	0x36B48000	0x36B48000 0x36B4800			
0E	0x 412008048120CFF7FEFFFF	0x 0x 412008048120CFF7FEFFFF 412008048120CFF			



2. 发射功率设置

RFM75 功率设置与 RFM73 不同,设置如下:

Bank1.Reg4<29:27>	Bank0.Reg6<2:1>	TX Power(dBm)	
7	3	4	
0	3	-1	
0	2	-7	
2	1	-12	
3	1	-12	
0	1	-18	
3	0	-18	
0	0	-25	
Others	-1		

3. RSSI 阈值

RFM75 RSSI 阈值不能调整。

250KHz		1MHz	2MHz	
RSSI 阈值(dBm)	-84	-80	-67	

RFM75 PowerUP 后第一包数据发送不成功的解决方法

RFM75 从POWER DOWN状态切换到POWER UP状态,发送第一包不成功,原因 是锁相环没有锁定,解决办法如下:

在正常发射数据前请按照以下流程操作:

power up=1

等待 2ms

操作 bank1 寄存器, 对寄存器 04 的 bit25 写 1

等待 20us

操作 bank1 寄存器, 对寄存器 04 的 bit25 写 0

等待 0.5ms.

再正常发射。

RFM75使用外部PA时,要将bank1 寄存器 04 设置为以下值: 5.

250K: 0xDB8A96C1 1M: 0x1B8296C1 2M: 0xDB8296C1



二、硬件处理注意事项

1. 5V IO 应用处理

RFM75 的 IO 正常应用是输入接口高电平为芯片电源电压(1.9V to 3.6V)。

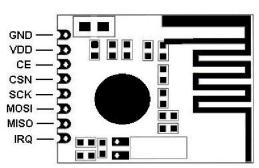
在有些应用中, IO 接口信号高电平比芯片电源电压高,例如芯片电源电压为 3.3V, IO 接口高 电平为 5V, 需要在 SCK, CE, CSN, MOSI 上分别串联 2kohm 电阳。



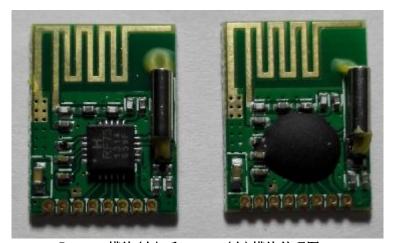
三、外观和封装

1. 模块脚位图

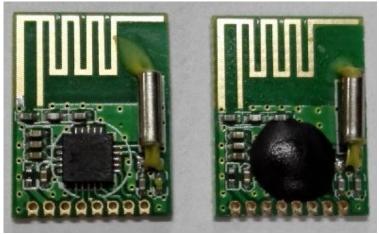
RFM75 和 RFM73 模块硬件脚位是完全兼容的,模块的尺寸大小没有变化。



2. RFM75 和 RFM73 外观有改变,对比图如下:



RFM73-P模块(左) 和 RFM73(右)模块外观图



RFM75-P模块(左) 和 RFM75(右)模块外观图



四、RFM73和RFM75模块参数对比

1. RFM73电气规格

Parameter (Condition)	Min	Typical	Max	Unit	Comment
	I.	JI			
	1.9	3.0	3.6	V	
	-40				
		1 . 2 /	. 02		1
	0.7VDD		5.25	V	
C					
	. 55	ı	0.0 + 22	<u> </u>	1
	VDD- 0.3		VDD	V	
				V	
		ı		<u> </u>	1
		2.5		пA	
		1		-	
	I	330		uri	1
	2400		2527	MHz	
1 0 1 1	2.00	16	2327		
	250	10	2000		
	230		2000	порь	
	-40	0	3	dBm	
	10	-			
I.					
1 1					
		1		-	
* *					
* *	1	23		1117-1	
		22		mΔ	
				-	
					High Sen mode
					High Sen mode
					High Sen mode
					Tilgii Scii illouc
` 1 /		1			
	1				-
ACS C/I 1MHz (250Kbps)		-11			
LACAC/LUVIMY L/NUK DDS)	1	-11	1	dB	
ACS C/I 2MHz (250Kbps)		-15		dB	
	Operating Condition Voltage Temperature Digital input Pin High level Low level Digital output Pin High level (IOH=-0.25mA) Low level(IOL=0.25mA) Normal condition Power Down current Standby-I current Standby-II current Normal RF condition Operating frequency Crystal frequency Air data rate Transmitter Output power Modulation 20 dB bandwidth (2Mbps) Modulation 20 dB bandwidth (1Mbps) Modulation 20 dB bandwidth (250Kbps) Out of band emission 2 MHz Out of band emission 4 MHz Current at -40 dBm output power Current at -30 dBm output power Current at -5 dBm output power Current at 5 dBm output power Current (2Mbps) Current (250Kbps) 1 E-3 BER 1 E-3 BER sensitivity (2Mbps) 1 E-3 BER sensitivity (1Mbps) 1 E-3 BER sensitivity (250Kbps) Co-channel C/I (2Mbps) ACS C/I 2MHz (2Mbps) ACS C/I 4MHz (2Mbps) ACS C/I 1MHz (1Mbps) ACS C/I 1MHz (1Mbps) ACS C/I 1MHz (1Mbps) ACS C/I 2MHz (1Mbps) ACS C/I 2MHz (1Mbps) ACS C/I 3MHz (1Mbps)	Operating Condition Voltage	Operating Condition	Operating Condition	Normal condition



2. RFM75电气规格

Name	Parameter (Condition)	Min	Typical	Max	Unit	Comment	
	Operating Condition						
VDD	Voltage	1.9	3.0	3.6	V		
TEMP	Temperature	-40	+27	+85	°C		
	Digital input Pin						
VIH	High level	0.7VDD		VDD+0.7	V VIL		
	Low level	VSS		0.3VDD	V		
	Digital output Pin						
VOH	High level (IOH=-0.25mA)	VDD- 0.3		VDD	V VOL		
	Low level(IOL=0.25mA)	0		0.3	V		
	Normal condition						
IVDD	Power Down current		3		uA		
IVDD	Standby-I current		50		uA		
IVDD	Standby-II current		300		uA		
	Normal RF condition						
FOP	Operating frequency	2400		2527	MHz		
FXTAL	Crystal frequency		16		MHz		
RFSK	Air data rate	250		2000	Kbps		
	Transmitter						
PRF	Output power		4		dBm		
PBW	Modulation 20 dB bandwidth(2Mbps)		TBD		MHz		
PBW	Modulation 20 dB bandwidth (1Mbps)		TBD		MHz		
PBW	Modulation 20 dB bandwidth (250Kbps)		TBD		KHz		
IVDD	Current at -25 dBm output power		9.8		mA		
IVDD	Current at -18 dBm output power		10.2		mA		
IVDD	Current at -12 dBm output power		10.8		mA		
IVDD	Current at -7 dBm output power		11.6		mA		
IVDD	Current at -1 dBm output power		13.4		mA		
IVDD	Current at 4 dBm output power		18		mA		
	Receiver		1 -				
IVDD	Current (2Mbps)		16.5		mA		
IVDD	Current (1Mbps)		16		mA		
IVDD	Current (250Kbps)		16		mA		
Max Input	1 E-3 BER		10		dBm		
RXSENS	1 E-3 BER sensitivity (2Mbps)		-88		dBm		
RXSENS	1 E-3 BER sensitivity (1Mbps)		-00 -91		dBm		
RXSENS	1 E-3 BER sensitivity (1Mbps) 1 E-3 BER sensitivity (250Kbps)		-91 -96		dBm dBm		



五、Contact Information

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